

UPSC ESE 2019

Main Exam Detailed Solutions

Electronics and Telecom. Engineering PAPER-II

EXAM DATE : 30-06-2019 | 2:00 PM to 5:00 PM

MADE EASY has taken due care in making solutions. If you find any discrepency/ error/typo or want to contest the solution given by us, kindly send your suggested answer with detailed explanations at info@madeeasy.in

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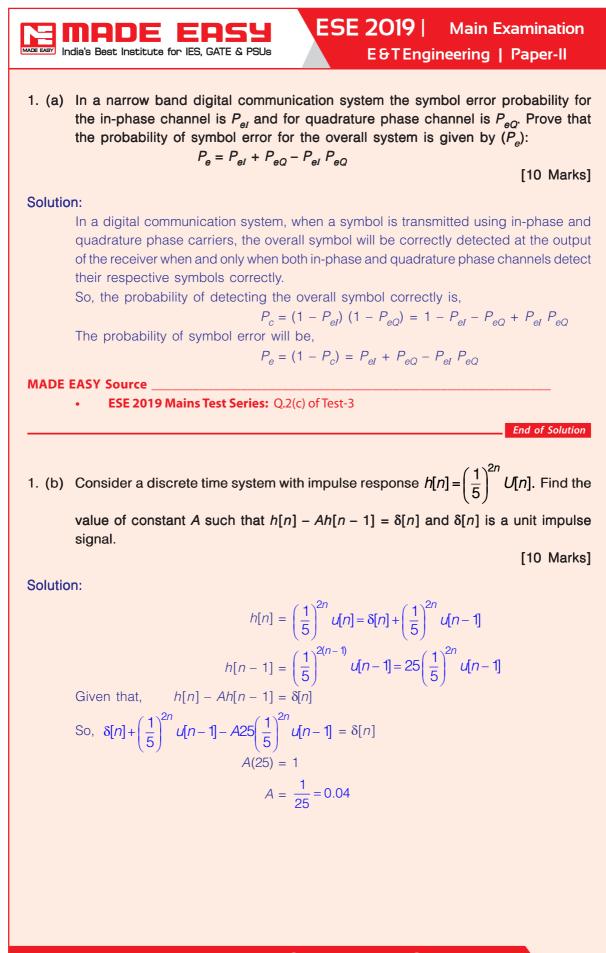
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Electronics and Telecom. Engineering Paper Analysis ESE 2019 Main Examination

SI.	Subjects	Marks
1.	Control Systems	70
2.	Electromagnetics	80
3.	Communication Systems	80
4.	Advanced Communication	100
5.	Advanced Electronics	80
6.	Computer Organization and Architecture	70
	Total	480

Scroll down for detailed solutions





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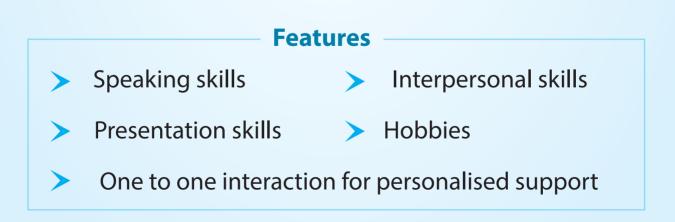
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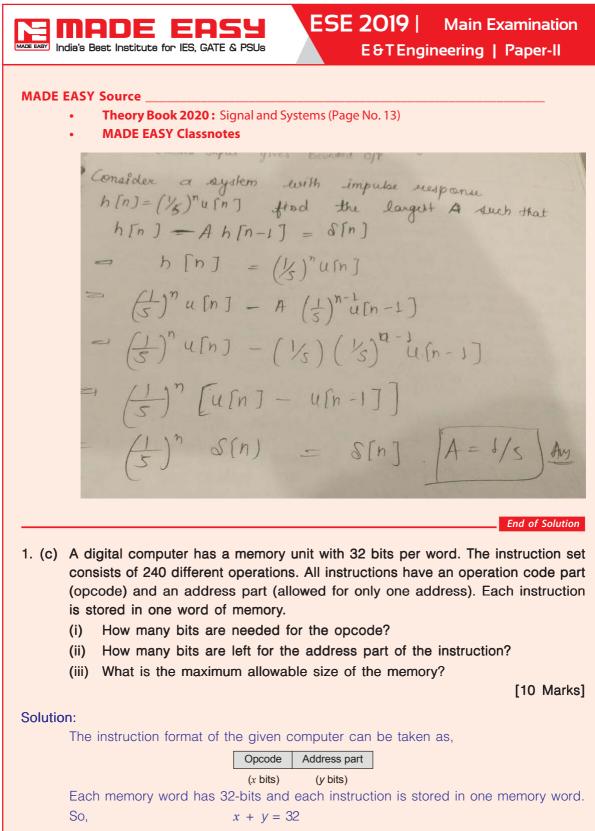
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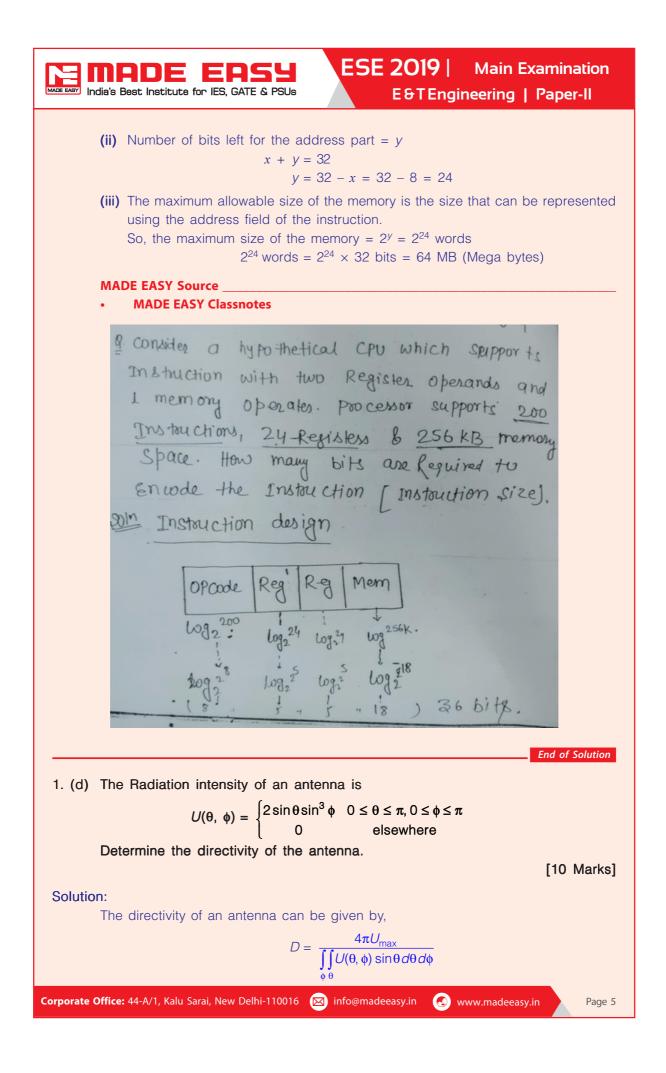


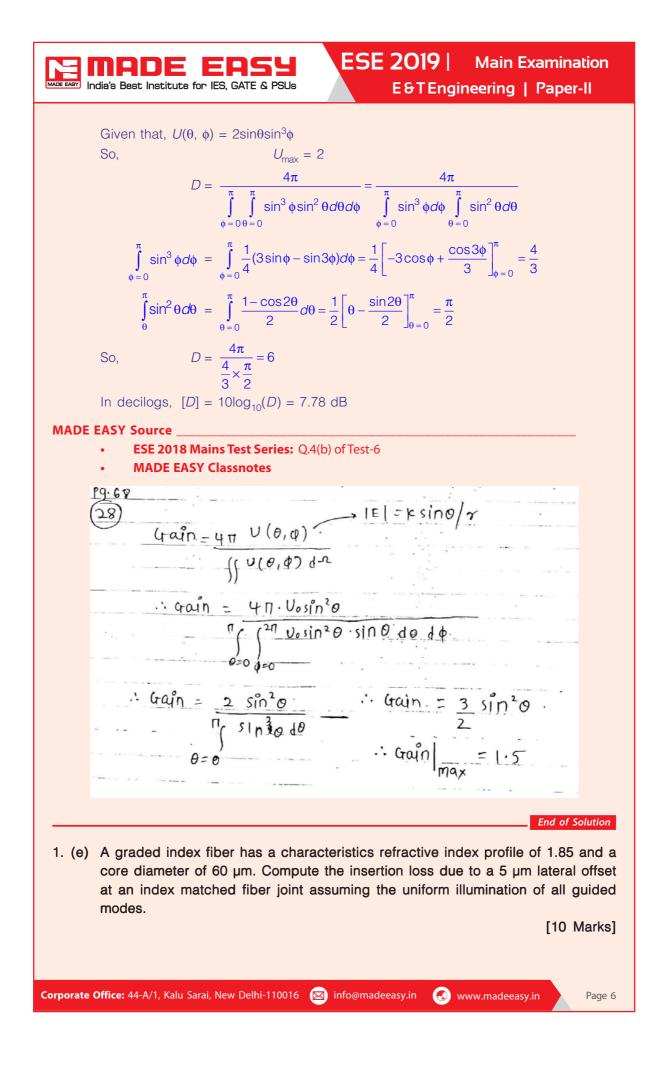
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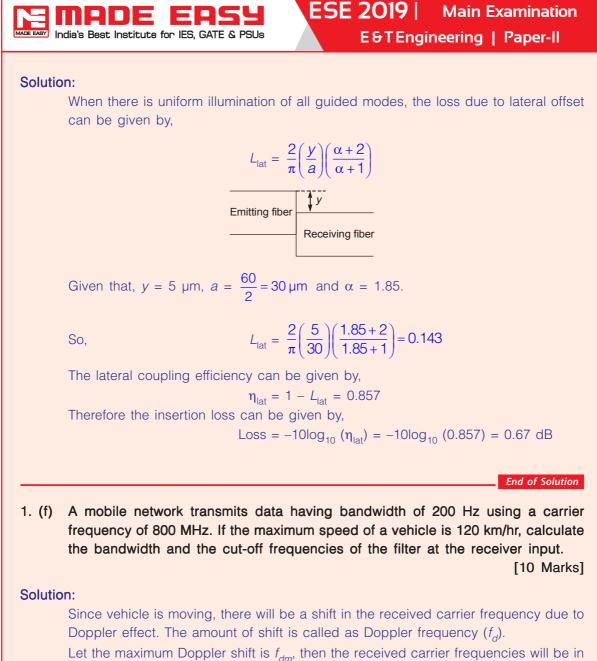


(i) Number of bits needed to represent opcode = x

$$x = \lceil \log_2(240) \rceil = \lceil 7.9 \rceil = 8$$







the range of $(f_c - f_{dm})$ to $(f_c + f_{dm})$.

$$f_{dm} = \frac{V_m}{C} f_c$$

 v_m = Maximum speed of the vehicle = 120 km/hr = $\frac{100}{3}$ m/s

$$c = 3 \times 10^8$$
 m/s and $f_c = 800$ MHz

So,

$$f_{dm} = \frac{100}{9 \times 10^8} \times 800 \times 10^6 = 88.88 \,\mathrm{Hz}$$

The data have bandwidth (B) of 200 Hz. So, the filter at the receiver input should have characteristics as follows:

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100





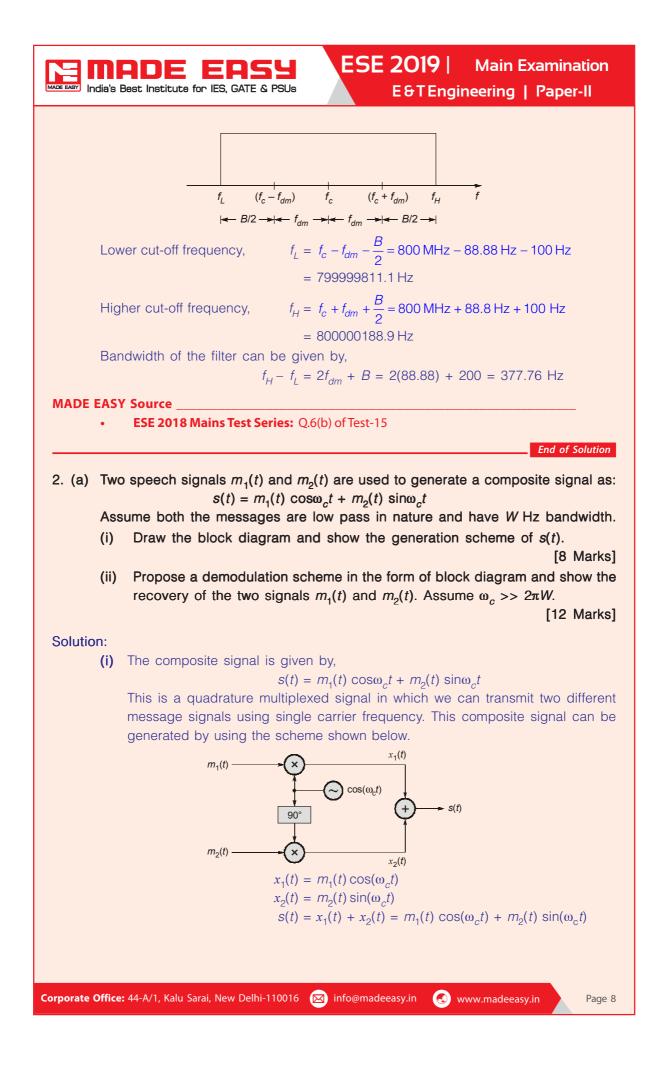
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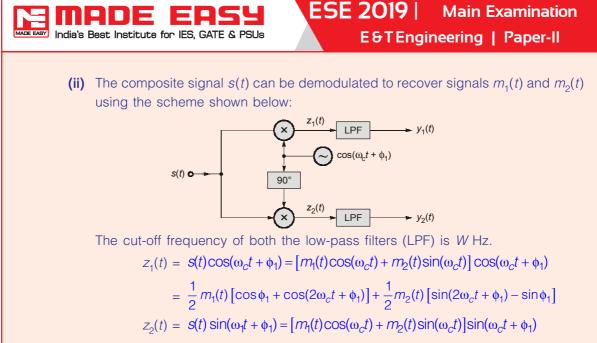
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$$= \frac{1}{2}m_1(t)\left[\sin(2\omega_c t + \phi_1) + \sin\phi_1\right] + \frac{1}{2}m_2(t)\left[\cos\phi_1 - \cos(2\omega_c t + \phi_1)\right]$$

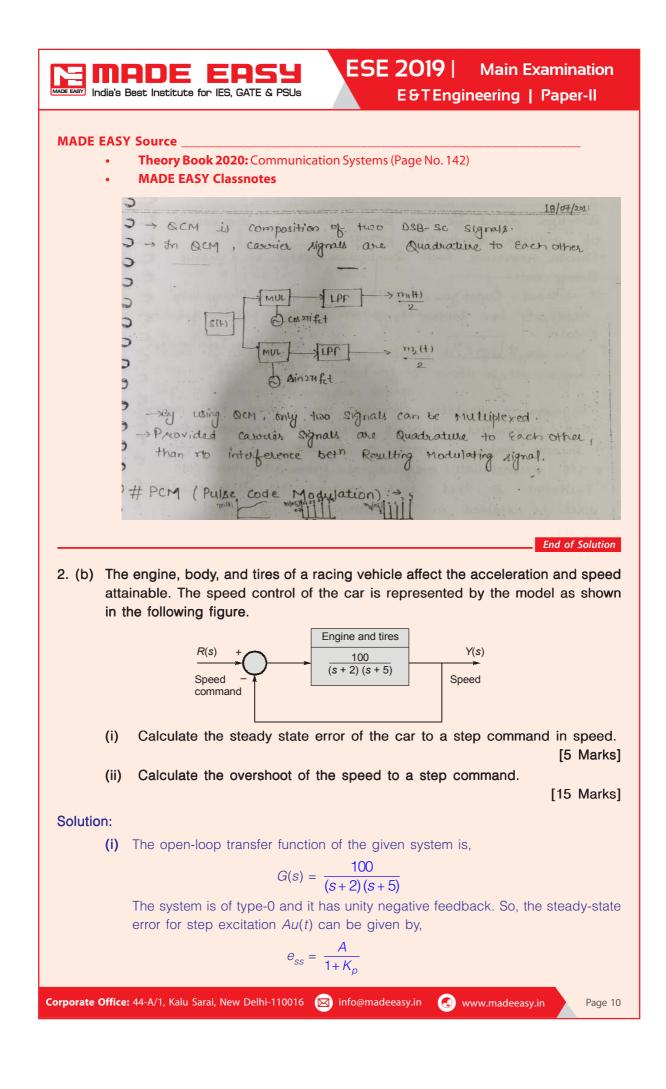
After posing $z_1(t)$ and $z_2(t)$ through LPF, we get,

$$y_{1}(t) = \frac{1}{2}m_{1}(t)\cos\phi_{1} - \frac{1}{2}m_{2}(t)\sin\phi_{1}$$
$$y_{2}(t) = \frac{1}{2}m_{2}(t)\cos\phi_{1} + \frac{1}{2}m_{1}(t)\sin\phi_{1}$$

If $\phi_1 = 0^\circ$, i.e. there is no phase difference between the transmitter carrier signal and the receiver local oscillator carrier signal. Then,

$$y_{1}(t) = \frac{1}{2}m_{1}(t) \propto m_{1}(t)$$
$$y_{2}(t) = \frac{1}{2}m_{2}(t) \propto m_{2}(t)$$

Hence the message signals $m_1(t)$ and $m_2(t)$ can be recovered from s(t) when $\phi_1 = 0^\circ$.



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 K_p = Position error constant = $\lim_{s \to 0} G(s)$

$$K_{p} = \lim_{s \to 0} G(s) = \frac{100}{2 \times 5} = 10$$
$$e_{ss} = \frac{A}{1 + 10} = \frac{A}{11}$$

For unit step excitation, $e_{ss} = \frac{1}{1+10} = \frac{1}{11} = 0.091$

(ii) The closed-loop transfer function of the given system is,

$$T(s) = \frac{100}{s^2 + 7s + 110}$$

By comparing the denominator of T(s) with the characteristic equation of a standard second order system, we get,

$$\omega_n^2 = 110 \Rightarrow \omega_n = \sqrt{110} \text{ rad/sec}$$

 $2\xi\omega_n = 7 \Rightarrow \xi = \frac{7}{2\sqrt{110}} = 0.334$

The maximum peak overshoot of the speed in response to a step command can be given by,

$$M_{p} = \frac{y(t_{p}) - y(\infty)}{y(\infty)} = e^{-\xi \pi / \sqrt{1 - \xi^{2}}} = e^{-\xi (0.334) / \sqrt{1 - (0.334)^{2}}} = 0.3285$$

 $\% M_p = 32.85\%$ **Note:** The closed-loop transfer function of the given system is deviated from that

of a standard second order system only by a scaling factor of $\left(\frac{110}{100}\right)$. But there

are no zeros in the transfer function. So, the formula of M_p of standard second order system is valid to calculate M_p of the given system.

- MADE EASY Source
 - GATE 2019 Online Test Series: Q.16 of Test-26

End of Solution

2. (c) A digital computer has memory capacity of 32767 words with 48 bits per word. The instruction code format consists of 8 bits for the operation part and 16 bits for the address part. Two instructions are packed in one memory word and 48 bit instruction register IR is available in the control unit. Formulate the procedure for fetching and executing the instructions for this computer.

[20 Marks] Solution: The format of the instructions can be given by <u>Opcode</u> Address (8-bits) (16-bits) ⇒24 bits Corporate Office: 44-A/1, Kalu Sarai, New Delhi-11001 (info@madeeasy.in) (info@madeeasy.in) Page 11

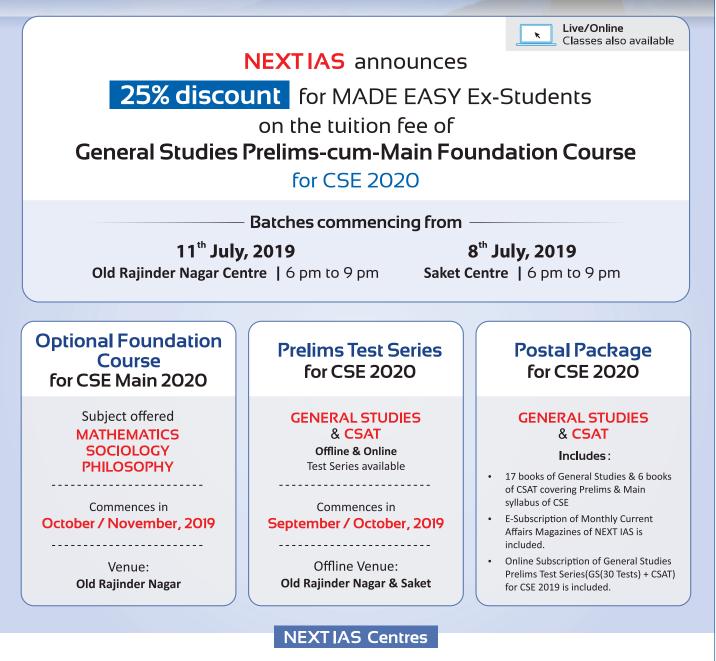


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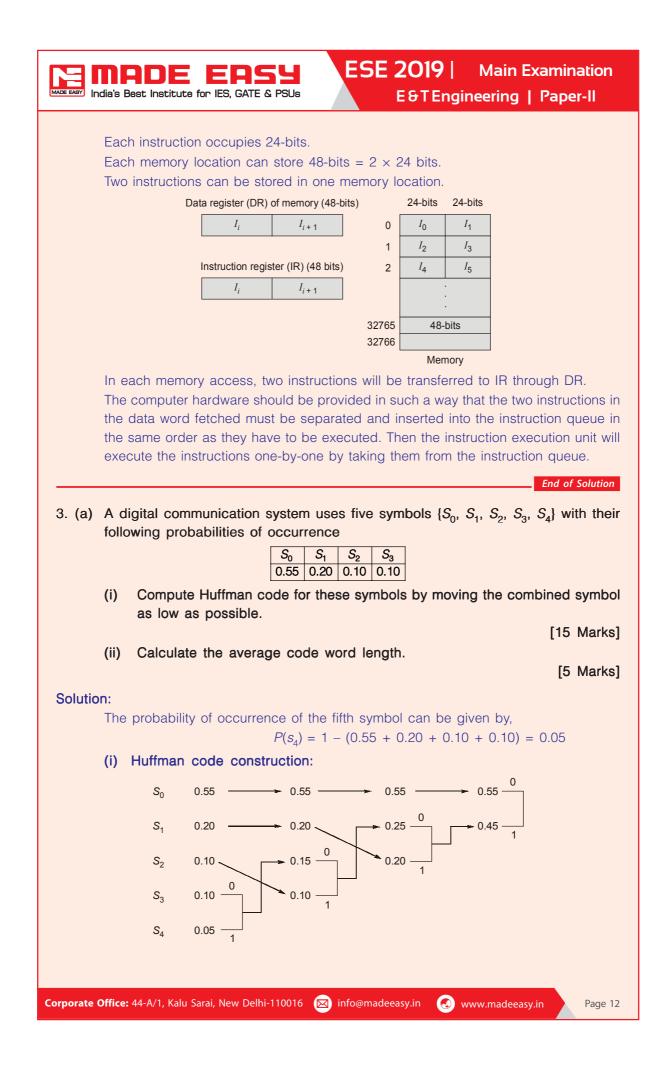
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The binary code words associated with each symbol can be tabulated as,

Symbol (S _i)	S ₀	S 1	S ₂	S ₃	S ₄
Probability, <i>P</i> (<i>S_i</i>)	0.55	0.20	0.10	0.10	0.05
Code word	0	11	101	1000	1001
Length of code word (l_i)	1	2	3	4	4

(ii) The average length of the code word can be given by,

$$\overline{L} = E[L] = \sum_{i=0}^{4} l_i P(S_i)$$

 $\overline{L} = (0.55 \times 1) + (0.20 \times 2) + (0.10 \times 3) + (0.10 \times 4) + (0.05 \times 4)$ = 1.85 binary digits/symbol

Entropy,

$$= -\sum_{i=0}^{4} P(S_i) \log_2 P(S_i) \simeq 1.82 \text{ bits/symbol}$$

Coding efficiency,

$$H = -\sum_{i=0}^{\infty} P(S_i) \log_2 P(S_i) \simeq 1.82 \text{ bits/s}$$

$$H = 1.82 = 0.004 \text{ (set) } 00.46\%$$

$$\eta = \frac{H}{L} = \frac{1.82}{1.85} = 0.984 \text{ (or) } 98.4\%$$

MADE EASY Source

- ESE 2019 Mains Test Series: Q.5(c) of Test-5
- ESE 2018 Mains Test Series: Q.3(a) of Test-15

End of Solution

3. (b) A unity feedback control system has $KG(s) = \frac{K(s+2)}{s(s+1)}$

Find the breakaway and entry points on the real axis. (i)

[10 Marks]

(ii) Find the gain and the roots when the real part of the complex roots are located at -2.

[10 Marks]

Solution:

(i) The open-loop transfer function of the given system is,

$$KG(s) = \frac{K(s+2)}{s(s+1)}$$

The characteristic equation of the system can be given by,

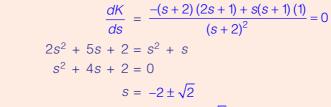
$$1 + KG(s) = 0 + \frac{K(s+2)}{s(s+1)} = 0$$

$$K = -\frac{s(s+1)}{(s+2)}$$

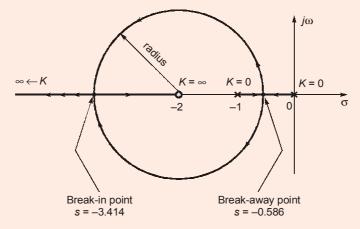
Solution of $\frac{dK}{ds} = 0$ yields break-away and break-in points.

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So, break-away point exists at $s = -2 + \sqrt{2} = -0.586$ Break-in point exists at $s = -2 - \sqrt{2} = -3.414$

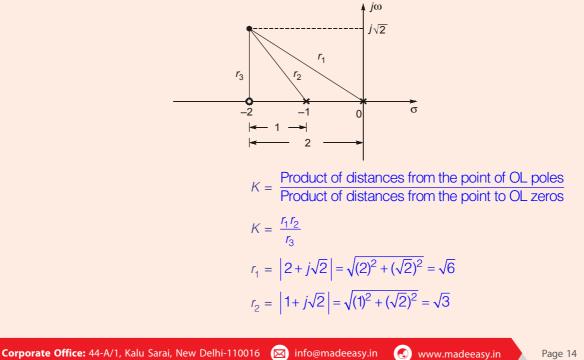


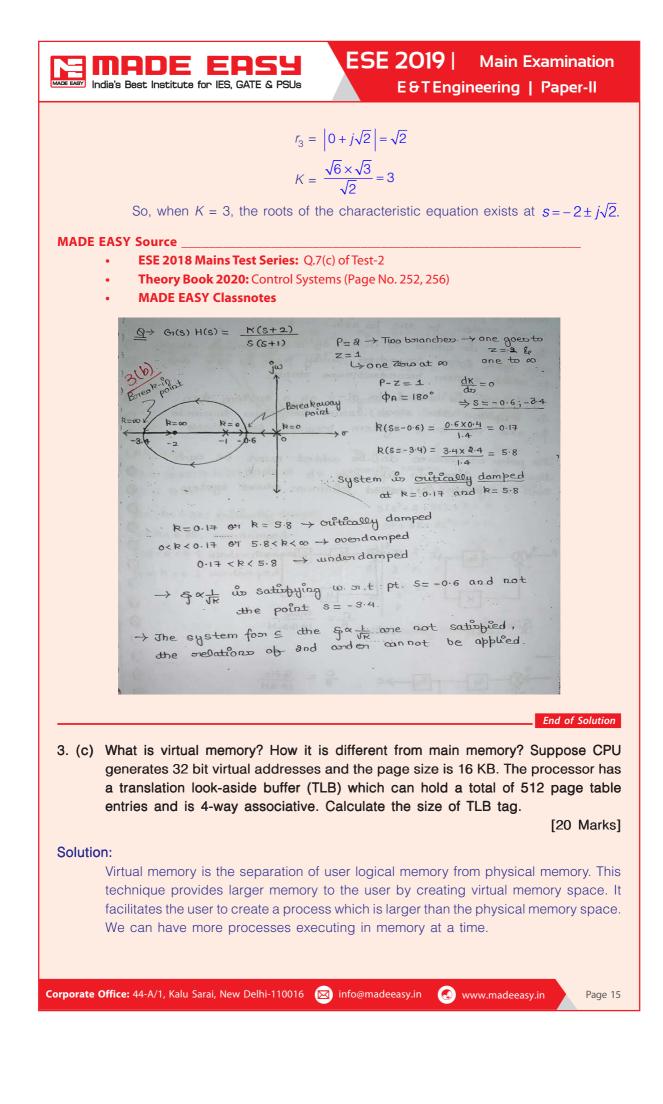
The radius of the circle = $\sqrt{2}$

Centre of the circle exists at s = -2

(ii) From the above root-locus diagram it is clear that, with real part as "-2", the roots exists on the root-locus at $s = -2 \pm i\sqrt{2}$

To determine gain K at $s = -2 \pm i\sqrt{2}$:







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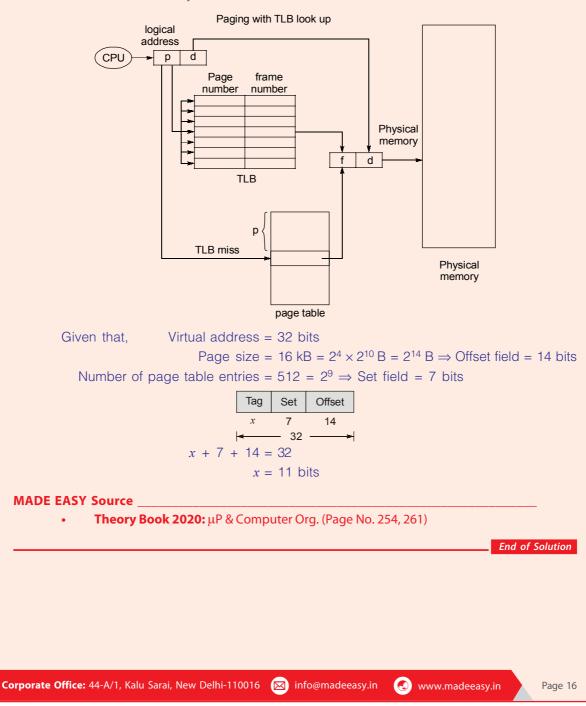
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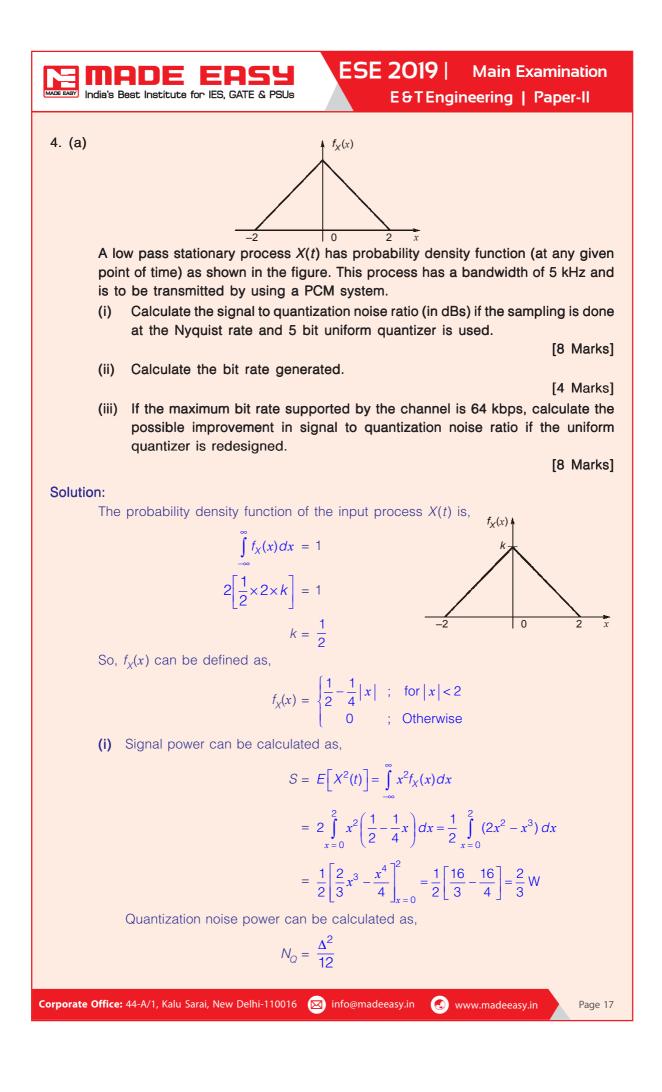


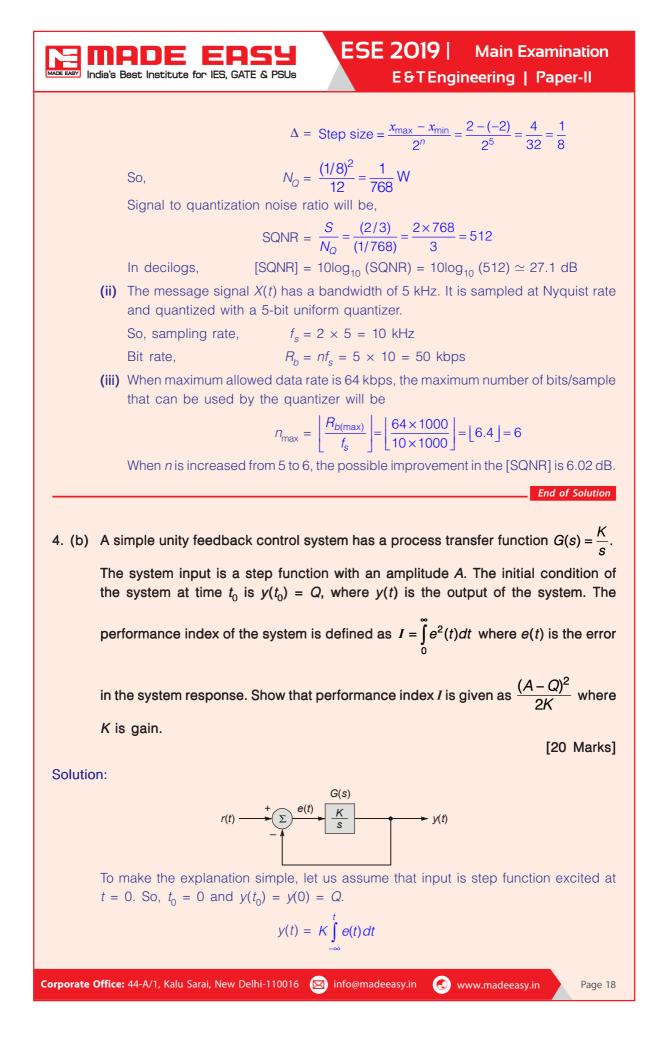
It increases degree of multiprogramming. With the virtual memory technique, we can execute a process which is only partially loaded in memory.

Paging with TLB (Translation Look-aside Buffer)

A TLB is on-chip hardware special cache which is part of memory-management unit. TLB is used in virtual-to-physical address translations so it is also called as addresstranslation cache. It is a cache that holds recently accessed page table entries. If address translation uses a TLB entry, access to the page table is avoided. TLB can cache only a few of page table entries. TLB is fully associative memory, so page numbers of all TLB entries are checked simultaneously for a match. TLB lookup is much faster than a memory access.









$$\frac{dy(t)}{dt} = Ke(t)$$

$$sY(s) - y(0) = KE(s)$$

$$sY(s) - Q = KE(s)$$

$$Y(s) = \frac{KE(s) + Q}{s}$$

$$E(s) = R(s) - Y(s)$$

For step excitation with an amplitude of A, $R(s) = \frac{A}{s}$.

So,

$$E(s) = \frac{A}{s} - \frac{KE(s) + Q}{s}$$
$$(s + K) E(s) = (A - Q)$$
$$E(s) = \frac{(A - Q)}{(s + K)}$$

By taking inverse Laplace transform, we get,

$$e(t) = (A - Q)e^{-Kt}$$

$$I = \int_{0}^{\infty} e^{2}(t) dt = \int_{0}^{\infty} (A - Q)^{2} e^{-2Kt} dt$$
$$= (A - Q)^{2} \left[-\frac{e^{-2Kt}}{2K} \right]_{0}^{\infty} = \frac{(A - Q)^{2}}{2K}$$

End of Solution

4. (c) What are the advantages and disadvantages of recursion? Write a code/pseudocode (in any standard programming language) with proper statements to accept a string as a command line argument and hence find its length.

[20 Marks]

Solution:

Advantages of recursion:

- We can create a simple and easy version of programs using recursion.
- Always recursion will be written in the name of recursive definition. It can be translated into C code very easily.
- We can avoid initialization of variable inside the functions, but iterative solutions are required to be initialized.
- Some specific applications are meant for recursion such as binary tree traversal, tower of Hanoi etc. can be easily understood.

Disadvantages of recursion:

- It occupies lot of memory.
- It consumes more time to get desired result.
- Function execution is slower than iterative method because of the overhead of calling functions repeatedly.





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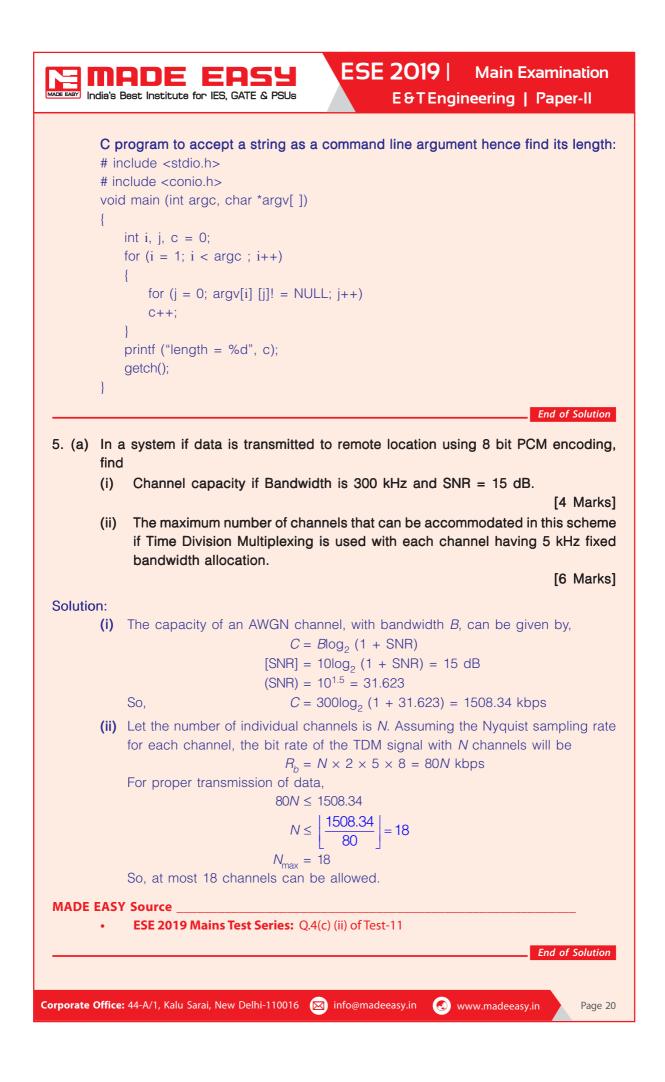
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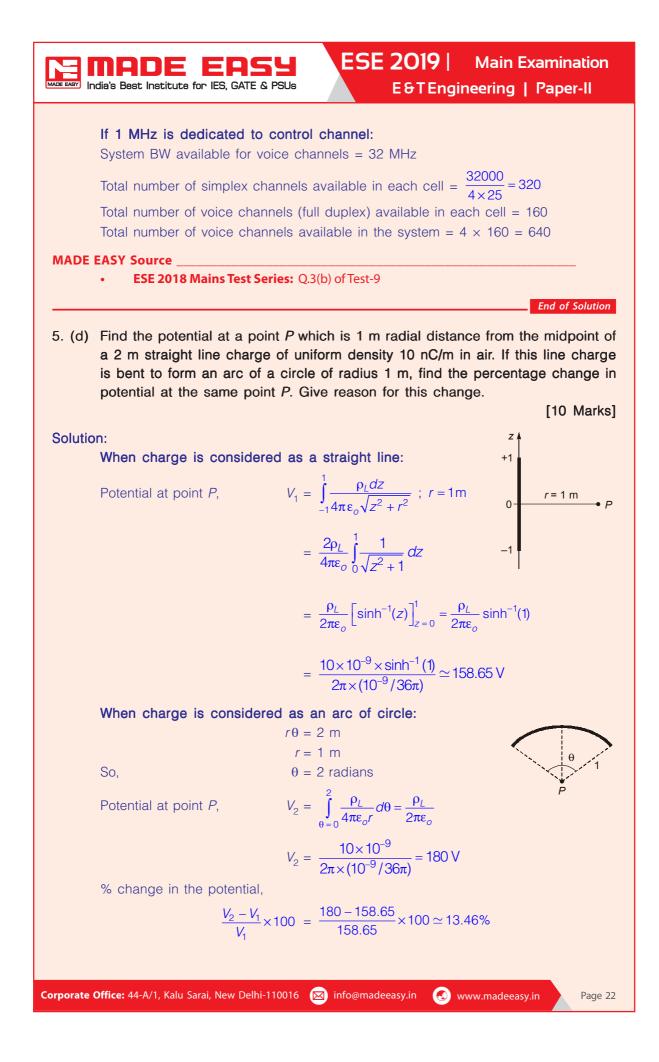


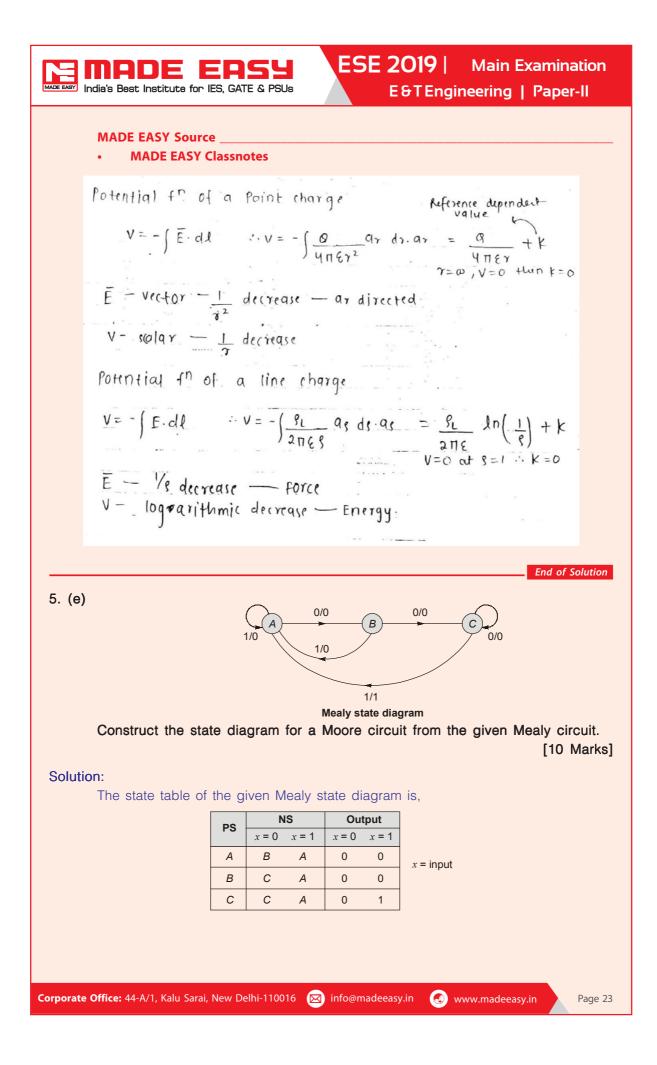
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ESE 2019 Main Examination E&TEngineering Paper-II
5. (b) A system is described by the state equations
$\dot{X} = \begin{bmatrix} 3 & 0 \\ -1 & 1 \end{bmatrix} X + \begin{bmatrix} -1 \\ 1 \end{bmatrix} U \text{ and } Y = \begin{bmatrix} 1 & 1 \end{bmatrix} X.$
Determine whether the system is controllable and observable.
[10 Marks]
$A = \begin{bmatrix} 3 & 0 \\ -1 & 1 \end{bmatrix}; B = \begin{bmatrix} -1 \\ 1 \end{bmatrix}; C^{T} = \begin{bmatrix} 1 \\ 1 \end{bmatrix}$
To check the controllability of the system: $\begin{bmatrix} -1 & -3 \end{bmatrix}$
$Q_C = \begin{bmatrix} B : AB \end{bmatrix} = \begin{bmatrix} -1 & -3 \\ 1 & 2 \end{bmatrix}$
$ Q_C = (-1 \times 2) - (-3 \times 1) = 1 \neq 0$
So, the given system is controllable. To check the observability of the system:
$Q_{c} = [C^T : A^T C^T]$
$A^{T} C^{T} = \begin{bmatrix} 3 & -1 \\ 0 & 1 \end{bmatrix} \begin{bmatrix} 1 \\ 1 \end{bmatrix} = \begin{bmatrix} 2 \\ 1 \end{bmatrix}$
$Q_O = \begin{bmatrix} 1 & 2 \\ 1 & 1 \end{bmatrix}$
$ Q_0 = (1 \times 1) - (2 \times 1) = -1 \neq 0$
So, the given system is observable.
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• Theory Book 2020: Control Systems (Page No. 423, Q.12.28)
End of Solution
5. (c) An analog cellular system has a total of 33 MHz of bandwidth and uses two 25 kHz simplex channels to provide full duplex voice and control channels. What is the number of channels available per cell for a frequency reuse factor of 4 cells? If 1 MHz is dedicated to a control channel then how many voice channels will be available for reuse factor of 4 cells. [10 Marks]
Solution:
Total number of cells in a cluster = 4 Total BW assigned to each cluster = System BW = 33 MHz BW of each simplex channel = 25 kHz
Total number of simplex channels available in each cell = $\frac{33000}{4 \times 25}$ = 330
Total number of full duplex channels available in each cell = 165
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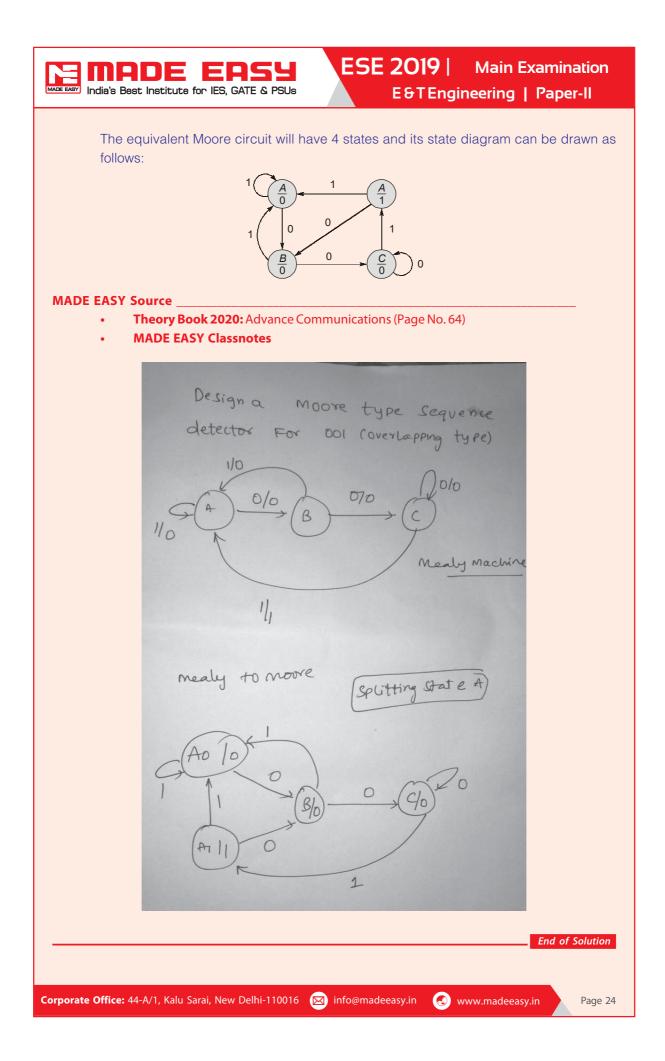
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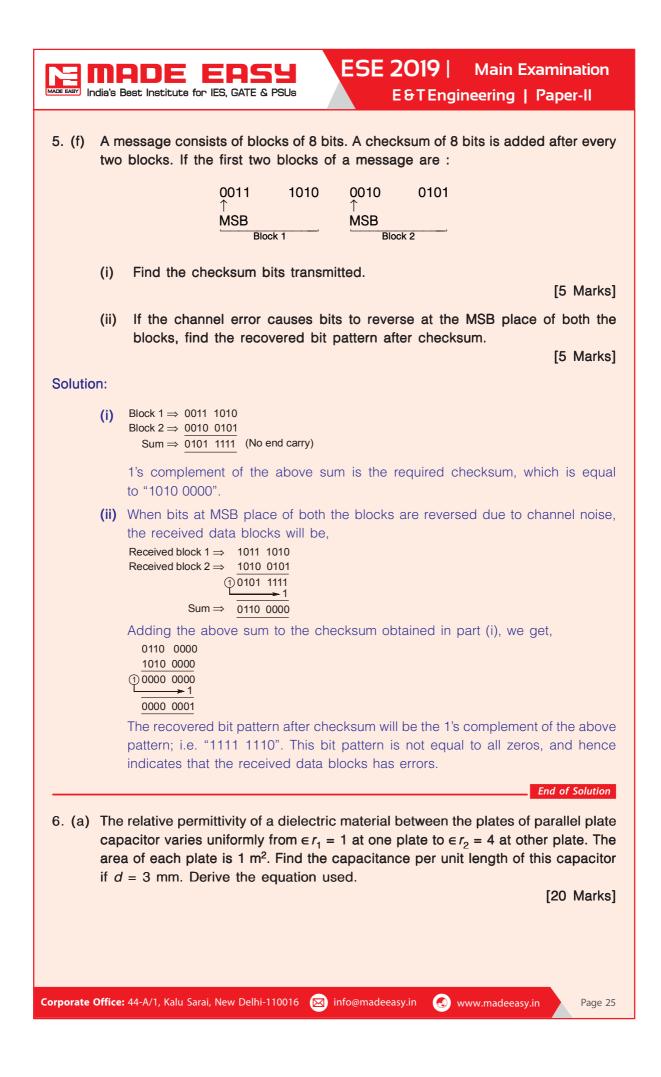
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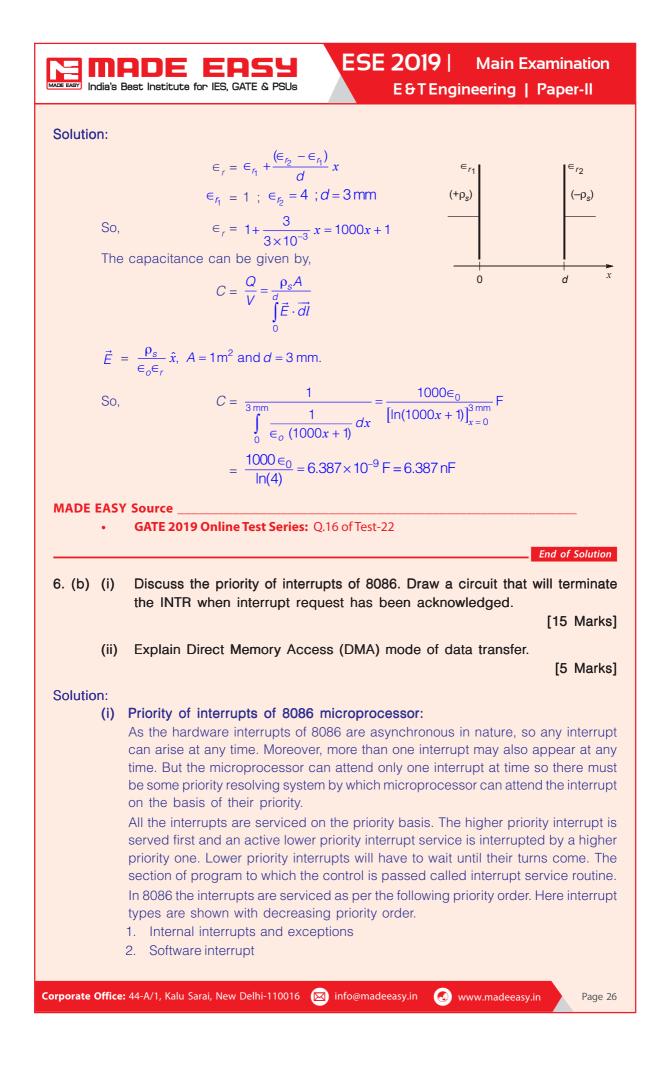
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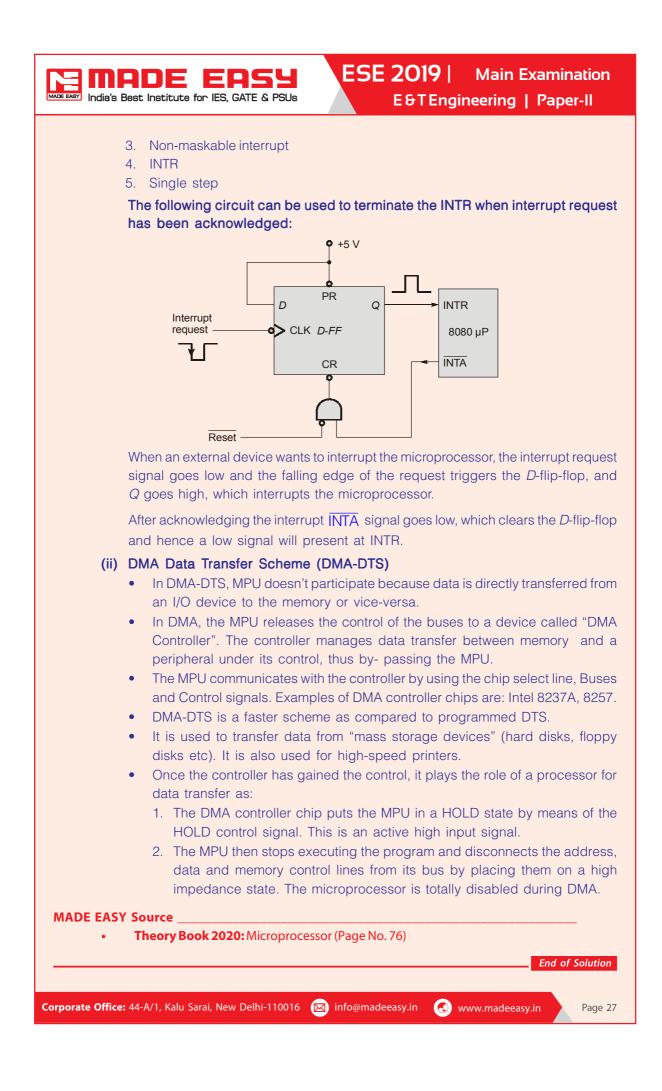
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6. (c) A network with 6 nodes with associated cost function is given in the Table below. Calculate the routing table using the shortest path Dijkstra's Algorithm assuming Node 1 as the source node. NC represents no connection between the nodes.

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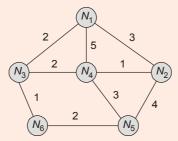
Node Number —	1	2	3	4	5	6
1	-	3	2	5	NC	NC
2	3	-	NC	1	4	NC
3	2	NC	-	2	NC	1
4	5	1	2	-	3	NC
5	NC	4	NC	3	_	2
6	NC	NC	1	NC	2	-

[20 Marks]

Solution:

ADE

From the given table, the network can be represented as,



The Dijkstra's algorithm always selects the shortest path possible from the source node to destination node.

So, the routing table with source node as N_1 can be given as follows:

Node	Path	Next hop to	Distance
N ₁	N ₁	_	0
N ₂	$N_1 \rightarrow N_2$	N ₂	3
N ₃	$N_1 \rightarrow N_3$	N ₃	2
N ₄	$N_1 \rightarrow N_3 \rightarrow N_4$	N ₃	4
N_5	$N_1 \rightarrow N_3 \rightarrow N_6 \rightarrow N_5$	N ₃	5
N ₆	$N_1 \rightarrow N_3 \rightarrow N_6$	N ₃	3

End of Solution

- 7. (a) A lossless line with $L = 0.5 \,\mu$ H/m and C = 150 PF/m is operated at a frequency 10 MHz. Find the shortest length of line at which it acts as
 - (i) 150 PF Capacitor on an open circuit and short circuit.
 - (ii) 2 µH Inductor on an open circuit and short circuit.

[20 Marks]

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Solution:

The line is lossless.

So,

$$Z_0 = \sqrt{\frac{L}{C}} = \sqrt{\frac{0.5 \times 10^{-6}}{150 \times 10^{-12}}} = 57.735 \,\Omega$$
$$v_p = \frac{1}{\sqrt{LC}} \frac{1}{\sqrt{75 \times 10^{-18}}} = 11.55 \times 10^7 \,\text{m/sec}$$
$$\lambda = \frac{v_p}{f} = \frac{11.55 \times 10^7}{10^7} = 11.55 \,\text{m}$$
$$\beta = \frac{2\pi}{\lambda} = 0.544 \,\text{rad/m}$$

Impedance at length (1) from the load end can be given by,

$$Z(l) = Z_0 \left[\frac{Z_L + jZ_0 \tan(\beta l)}{Z_0 + jZ_0 \tan(\beta l)} \right]$$

When line is open circuited (i.e., $Z_L = \infty$),

$$Z_{\rm OC}(l) = -jZ_0 \cot(\beta l) = -j\frac{Z_0}{\tan(\beta l)}$$

When line is short circuit (i.e., $Z_L = 0$), $Z_{SC}(l) = jZ_0 \tan(\beta l)$

(i) To act as a capacitor of 150 pF:

$$Z(l) = \frac{1}{j\omega C} = \frac{1}{j(2\pi \times 10^7 \times 150 \times 10^{-12})} = -j106.1\Omega$$

With open circuit, the minimum length of the line required is,

$$l_{\min} = \frac{1}{\beta} \tan^{-1} \left(\frac{57.735}{106.1} \right) \simeq 0.916 \,\mathrm{m}$$

With short circuit, the minimum length of the line required is,

$$l_{\min} = \frac{1}{\beta} \left[\pi - \tan^{-1} \left(\frac{106.1}{57.735} \right) \right] = 3.8 \text{ m}$$

(ii) To act as an inductor of 2 μ H:

 $Z(l) = j\omega L = j(2\pi \times 10^7 \times 2 \times 10^{-6}) = j125.664 \ \Omega$ With open circuit, the minimum length of the line required is,

$$l_{\min} = \frac{1}{\beta} \left[\pi - \tan^{-1} \left(\frac{57.735}{125.664} \right) \right] = 4.983 \,\mathrm{m}$$

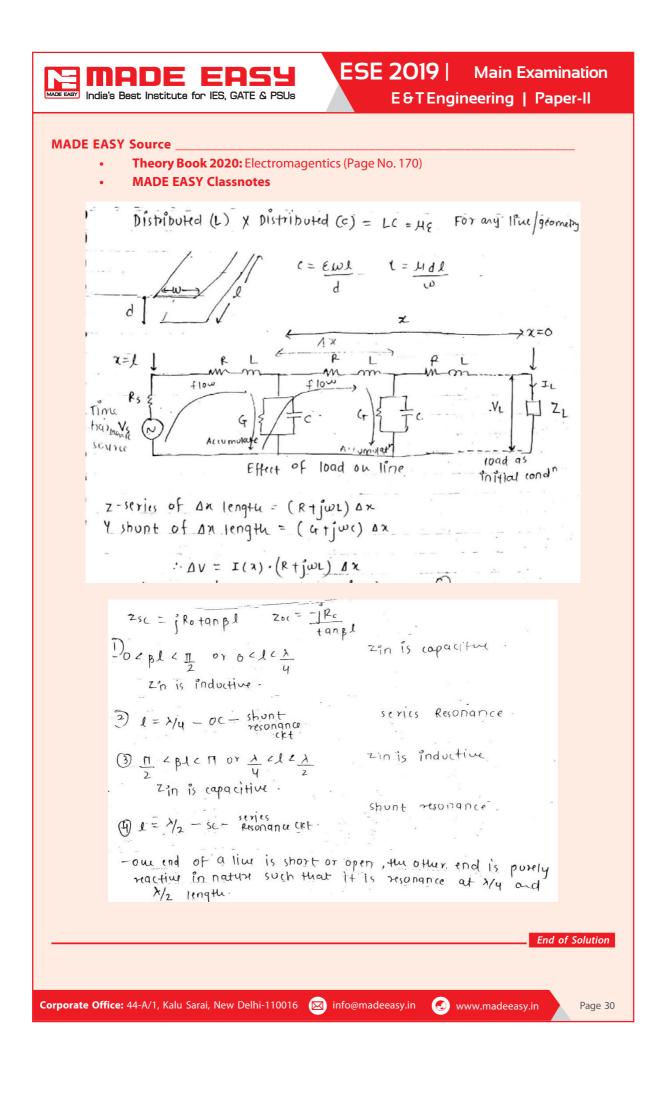
With short circuit, the minimum length of the line required is,

$$l_{\min} = \frac{1}{\beta} \tan^{-1} \left(\frac{125.664}{57.735} \right) = 2.096 \,\mathrm{m}$$

The results obtained in part (i) and part (ii) can be tabulated as follows:

	<i>l</i> _{min} with open circuit	<i>l</i> _{min} with short circuit
To act as 150 pF capacitor	0.916 m	3.8 m
To act as 2 µH inductor	4.983 m	2.096 m

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7. (b) (i) Implement the following Boolean functions using PLA: Sum (A, B, C_{in}) = $\Sigma m(1, 2, 4, 7)$ C_{out} (A, B, C_{in}) = $\Sigma m(3, 5, 6, 7)$ [10 Marks] (ii) Explain photolithography process. Also, explain the importance of photoresists. [10 Marks]			
Solution: ()			
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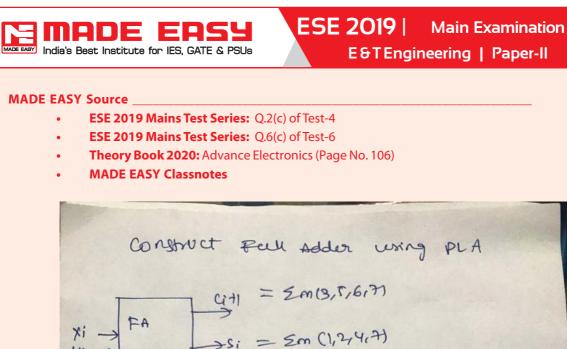
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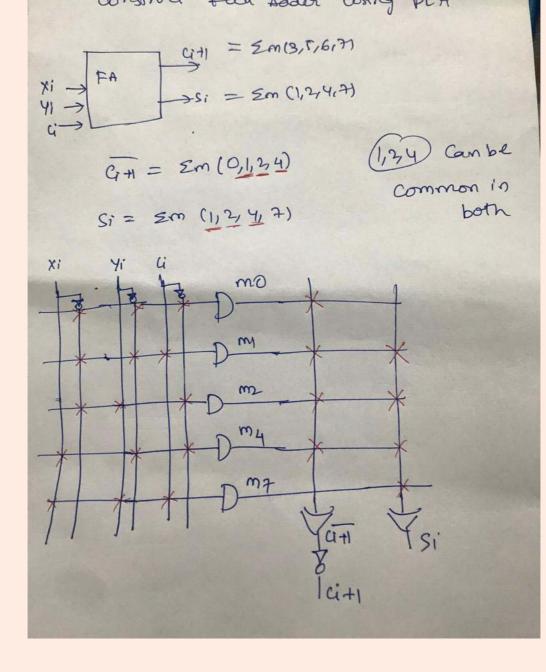
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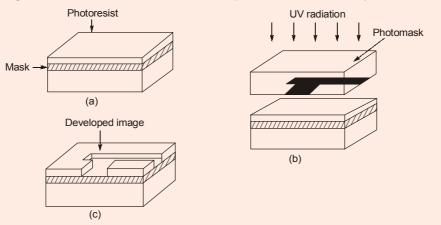
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ESE 2019 **Main Examination** E&TEngineering | Paper-II

(ii) For the fabrication of semiconductor devices, selective doping is often necessary. This means that certain regions of the wafer have to be protected against doping during diffusion or ion-implantation. In general, this is done by covering the entire sample by a protective (masking) layer and then removing this mask layer at some selected regions by a process called photolithography. Afterwards, diffusion or ionimplantation is carried out and doping takes place only in the regions not protected by the mask. The most commonly used mask material in silicon technology is silicon dioxide (SiO₂) and it can be easily grown on silicon by thermal oxidation as discussed in the previous section. For compound semiconductors, SiO₂ and/or Si₃N₄ deposited by chemical vapour deposition can be used as masks. Since ionimplantation is a relatively low temperature process, photoresist itself can be used as a mask against implantation.

Once the mask layer is grown or deposited on the semiconductor surface, it must be patterned. That is, the mask should be retained only over certain selected regions and removed from the rest of the surface. Patterning is a two-step process. In the first step, a photosensitive material (photoresist) is spin-coated on the entire sample surface. There are two types of photoresist, namely positive and negative. In optical photolithography, the photoresist-coated wafer is exposed to UV light through an appropriate mask plate (or photomask). Certain regions on the mask plate are transparent, and the rest is opaque. In case of positive photoresist, the photoresist exposed to UV light is softened and is therefore easily removed in a developer solution. In case of negative photoresist, only the exposed resist remains and the unexposed resist is removed by the developer solution. Thus, the mask pattern (or its negative) is transferred onto the resist-coated sample after the exposed (or unexposed) resist is removed in the developer solution. The following figures (a), (b), and (c) illustrate the process schematically.



Different steps in photolithography process showing the transfer of patterns

In the second step of patterning, the mask is removed (etched) from the regions no longer protected by photoresist (also called opening windows in the mask). If the masking layer is SiO₂, etching is usually done by dipping the sample in hydrofluoric acid (wet chemical etching), which etches SiO₂ in the regions which are not protected by the photoresist. After the selective removal of oxide, photoresist is removed from everywhere. The sample is then washed in de-ionized water, dried



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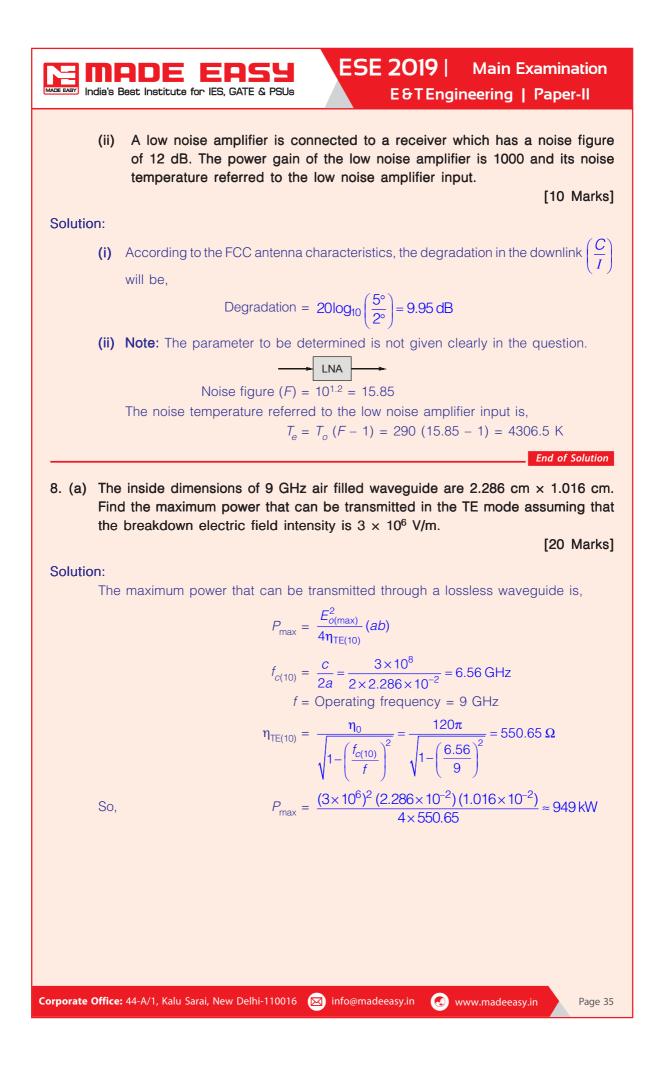
thoroughly, and is ready for diffusion/implantation. However, if photoresist itself is the mask used against ion-implantation, it is not necessary to grow and selectively etch the oxide.

Optical lithography using deep UV light is by far the most widely used lithography technique today. The minimum feature size which can be obtained by the photolithography process depends on the wavelength of the UV radiation, and lower wavelengths are used for better resolution. Electron beam lithography and X-ray lithography have also been used to reduce the minimum feature size. Electron beam lithography allows direct writing on the sample (no patterned mask plate is needed as the electron beam is directly raster-scanned on the photoresist). Due to the very small electron beam size, high resolution can be achieved. However, scanning the entire wafer is a very slow process and hence not suitable for large scale production. On the other hand, it is difficult to prepare a suitable mask plate for X-ray lithography. Thus, these techniques so far have found only limited application.

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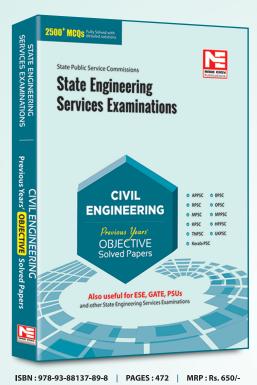
- ESE 2019 Mains Test Series: Q.3(b) of Test-4
- **Theory Book 2020:** Advance Electronics (Page No. 9)
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Explain the steps of photolithography? Photolithography is process of bransfer of pattern. It is the most important Step in the Fabrication sequence. The steps The ster). Apply photoresist photoresist is photoresist photoresist is photoresist opplied by Spin Coati End of Solution 7. (c) (i) Calculate the degradation in the downlink $\left(\frac{C}{I}\right)$ ratio when orbital spacing between the satellites is reduced from 5° to 2°, all the other factors remaining unchanged. Assume antenna characteristics as per Federal Communications Commission (FCC) norms. [10 Marks] Corporate Office: 44-A/1, Kalu Sarai, New Delhi-110016 🛛 info@madeeasy.in 🕢 www.madeeasy.in Page 34





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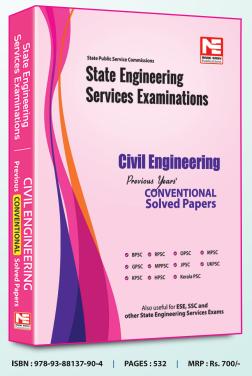
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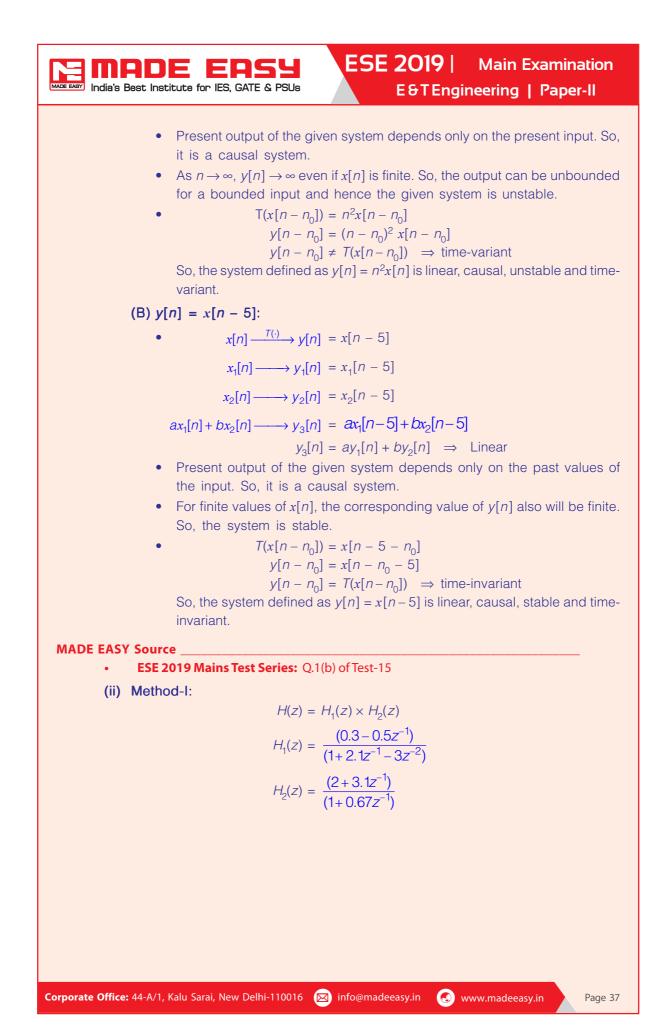
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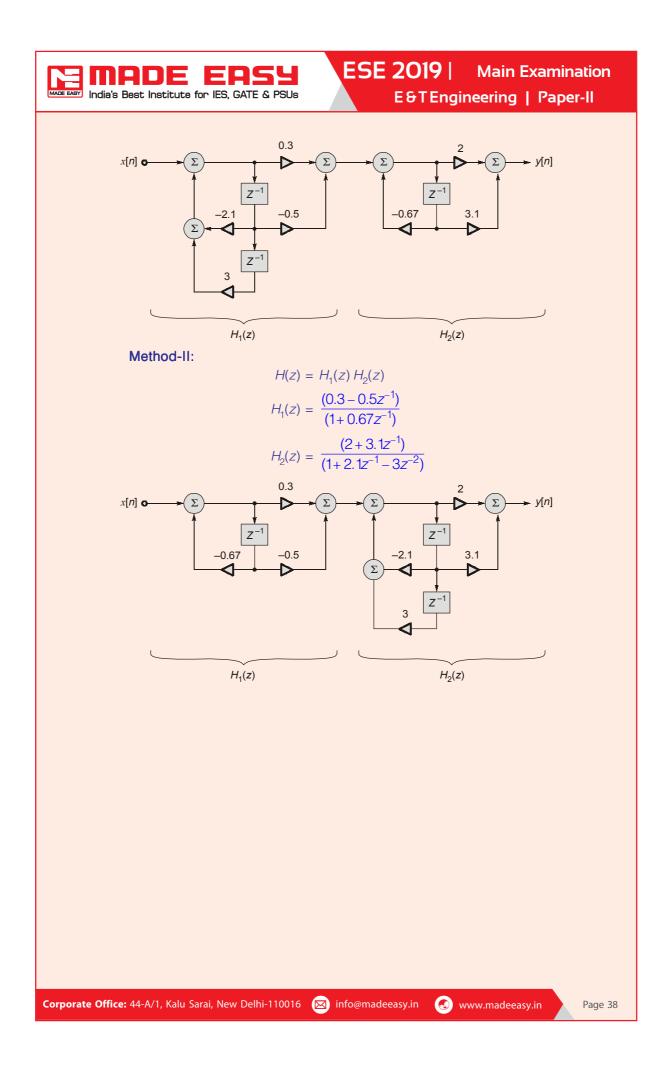


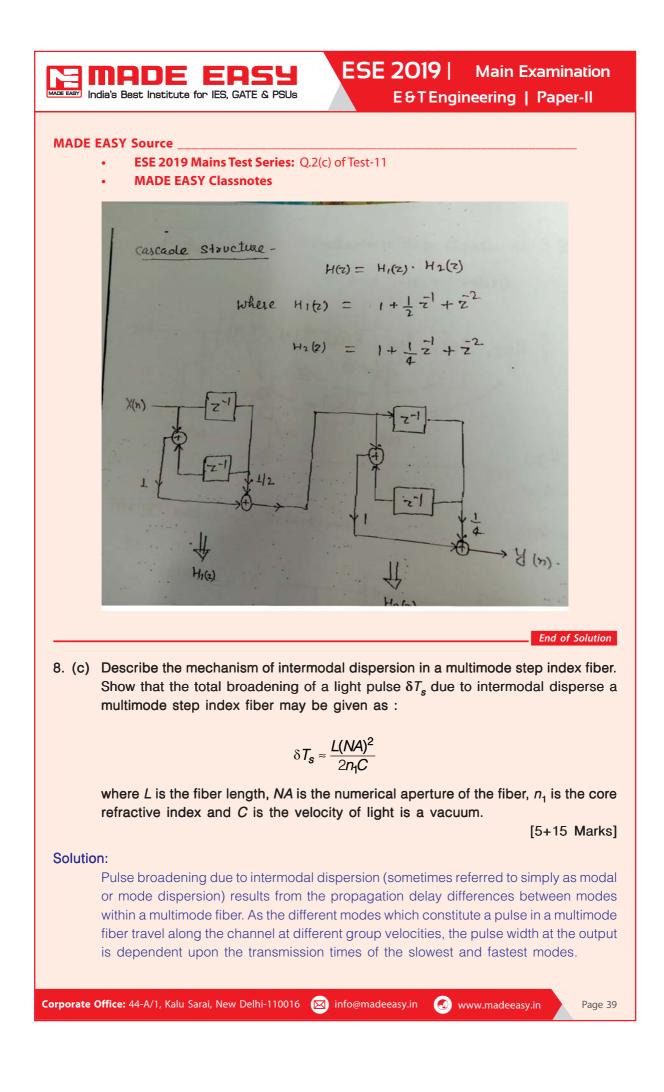
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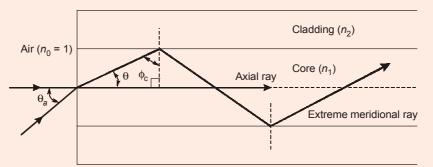








Using the ray theory model, the fastest and slowest modes propagating in the step index fiber may be represented by the axial ray and the extreme meridional ray (which is incident at the core-cladding interface at the critical angle ϕ_c) respectively. The paths taken by these two rays in a perfectly structured step index fiber are shown in figure below.



The delay difference between these two rays when traveling in the fiber core allows estimation of the pulse broadening resulting from intermodal dispersion within the fiber. As both rays are traveling at the same velocity within the constant refractive index fiber core, the delay difference is directly related to their respective path lengths within the fiber.

The time taken for the axial ray to travel along a fiber of length *L* gives the minimum delay time T_{min} and:

$$T_{\min} = \frac{\text{Distance}}{\text{Velocity}} = \frac{L}{(c/n_1)} = \frac{Ln_1}{c}$$
 ...(i)

where n_1 is the refractive index of the core and *c* is the velocity of light in a vacuum. The extreme meridional ray exhibits the maximum delay time T_{max} where:

$$T_{\max} = \frac{L/\cos\theta}{c/n_1} = \frac{Ln_1}{\cos\theta} \qquad \dots (ii)$$

Using Snell's law of refraction at the core-cladding interface,

$$\sin\phi_c = \frac{n_2}{n_1} = \cos\theta \qquad \dots (iii)$$

where n_2 is the refractive index of the cladding. Furthermore, substituting into equation (ii) for $\cos\theta$ gives:

$$T_{\rm max} = \frac{Ln_{\rm fl}^2}{Cn_2} \qquad \dots ({\rm iv})$$

The delay difference δT_s between the extreme meridional ray and the axial ray may be obtained by,

$$\delta T_{s} = T_{max} - T_{min} = \frac{Ln_{1}^{2}}{cn_{2}} - \frac{Ln_{1}}{c}$$
$$= \frac{Ln_{1}^{2}}{cn_{2}} \left(\frac{n_{1} - n_{2}}{n_{1}}\right) \qquad \dots (v)$$

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$$\simeq \frac{Ln_1^2\Delta}{cn_2}$$
 when $\Delta << 1$...(vi)

where Δ is the relative refractive index difference.

However, when
$$\Delta << 1$$
, $\Delta \simeq \frac{n_1 - n_2}{n_2}$...(vii)

Hence rearranging equation (v):

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$$\delta T_s = \frac{Ln_1}{c} \left(\frac{n_1 - n_2}{n_2} \right) \simeq \frac{Ln_1 \Delta}{c}$$

 Δ also can be related to numerical aperture (NA) as,

$$(NA) = n_1 \sqrt{2\Delta} \implies \Delta = \frac{(NA)^2}{2n_1^2}$$

So,

$$\delta T_{s} \simeq \frac{L(NA)^{2}}{2n_{1}c}$$

MADE EASY Source _

- ESE 2019 Mains Test Series: Q.8(a) of Test-13 •
- Theory Book 2020: Advance Communications (Page No. 71) •

End of Solution

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